Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1 – 54. (Canceled)

55. (currently amended) A <u>circuit circuitry</u> component, <u>used to be connected to a substrate comprising a first pad with a sidewall not covered by a solder mask, comprising:</u>

a semiconductor device;

a metal pillar over said semiconductor device, wherein said metal pillar has a thickness of between 10 and 100 microns;

a metal layer over said metal pillar, wherein said metal layer has a bottom surface partially covered by said metal pillar and partially not covered by said metal pillar; and

a solder metal over said metal layer, wherein said solder metal is used to be bonded to said first pad.

56. (currently amended) The <u>circuit circuitry</u>-component of Claim 55, <u>wherein said</u> solder metal is bonded to said first pad. <u>used to be connected to a substrate</u>,

Application no. 09/837,007

MEG01-004CC

wherein said substrate has a pad having an edge not covered by a solder mask, and wherein said solder metal is bonded to said pad.

57. (currently amended) The <u>circuit component chip package</u> of Claim 55, wherein the distance between <u>a sidewall an edge</u> of said metal layer and <u>a sidewall an edge</u> of said metal pillar is greater than 0.2 microns.

58. (currently amended) The <u>circuit component chip package</u> of Claim 55, wherein said semiconductor device comprises a <u>second pad and a passivation layer</u>, said <u>second pad exposed by an opening in said passivation layer</u>, wherein said metal pillar is over said <u>second pad</u>.

59. (currently amended) The <u>circuit component chip package</u> of Claim <u>58 55</u> further comprising a barrier <u>layer</u> between said <u>metal pillar bump</u> and said <u>second</u> pad.